

PMF170XP 20 V, 1 A P-channel Trench MOSFET 29 October 2013

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a SOT323 (SC-70) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low R_{DSon}
- Very fast switching
- Trench MOSFET technology

3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} 25 °C	[1]	-	-	-1	А
Static charact	eristics					_	
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -1 A; T _j = 25 °C		-	175	200	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain		G
			SC-70 (SOT323)	017aaa094

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PMF170XP	SC-70	plastic surface-mounted package; 3 leads	SOT323			

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMF170XP	XD%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} 25 °C	[1]	-	-1	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	[1]	-	-0.7	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-4	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	290	mW
			[1]	-	360	mW
		T _{sp} = 25 °C		-	1670	mW
Tj	junction temperature			-55	150	°C
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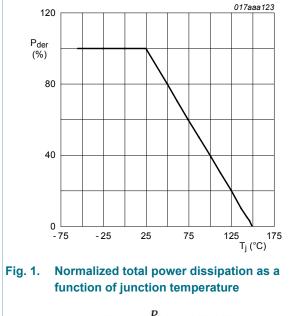
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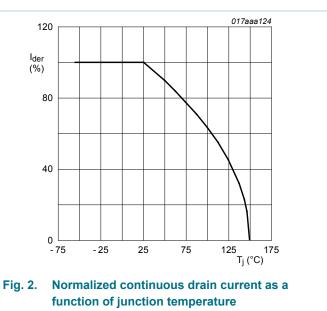
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Symbol	Parameter	Conditions		Min	Мах	Unit	
T _{amb}	ambient temperature			-55	150	°C	
T _{stg}	storage temperature			-65	150	°C	
Source-drain diode							
I _S	source current	T _{amb} = 25 °C	[1]	-	-0.4	А	

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

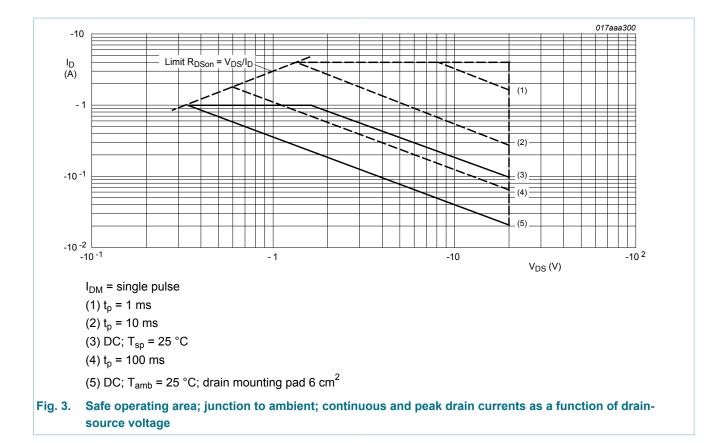


$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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9. Thermal characteristics

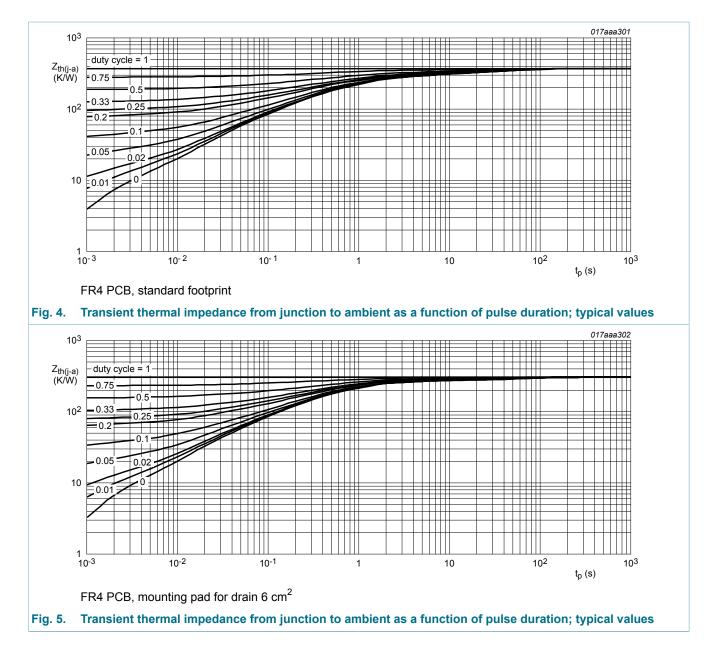
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1]	-	377	430	K/W
	from junction to ambient		[2]	-	305	350	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	65	75	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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10. Characteristics

Table 7. Cha	aracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static charact	eristics						
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -250 μA; V _{GS} = 0 V; T _j = 25 °C		-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 A; V _{DS} = V _{GS} ; T _j = 25 °C		-0.65	-0.9	-1.15	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C		-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C		-	-	-10	μA
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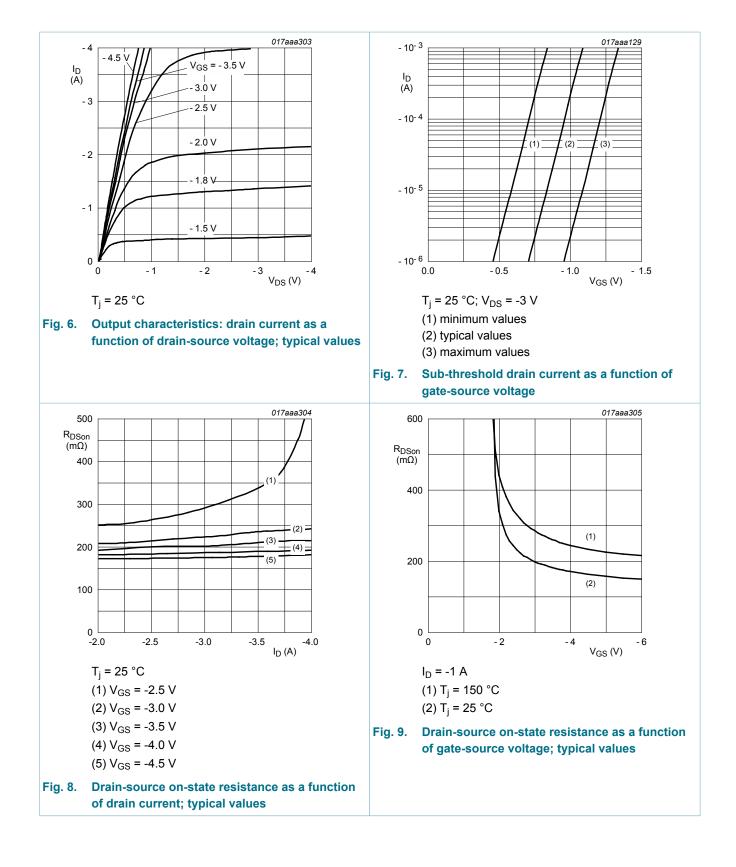
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GSS}	gate leakage current	V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
		V_{GS} = 12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -1 A; T _j = 25 °C	-	175	200	mΩ
	resistance	V_{GS} = -4.5 V; I _D = -1 A; T _j = 150 °C	-	250	284	mΩ
		V_{GS} = -2.5 V; I _D = -1 A; T _j = 25 °C	-	240	300	mΩ
9 _{fs}	forward transconductance	V _{DS} = -5 V; I _D = -1 A; T _j = 25 °C	-	1.9	-	S
Dynamic cl	haracteristics					
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -1 A; V _{GS} = -4.5 V; T _j = 25 °C	-	2.6	3.9	nC
Q _{GS}	gate-source charge		-	0.63	-	nC
Q _{GD}	gate-drain charge		-	0.53	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	280	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	43	-	pF
C _{rss}	reverse transfer capacitance	-	-	30	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -1 A; V _{GS} = -4.5 V;	-	10	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	16	-	ns
t _{d(off)}	turn-off delay time		-	31	-	ns
t _f	fall time		-	13	-	ns
Source-dra	in diode	· · ·	1			
V _{SD}	source-drain voltage	I _S = -0.4 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V

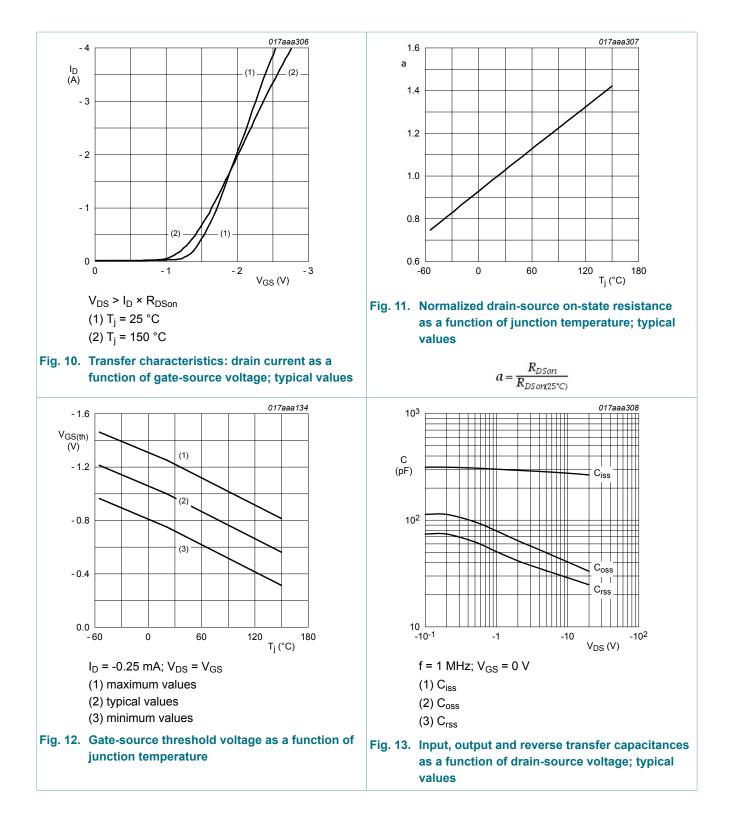
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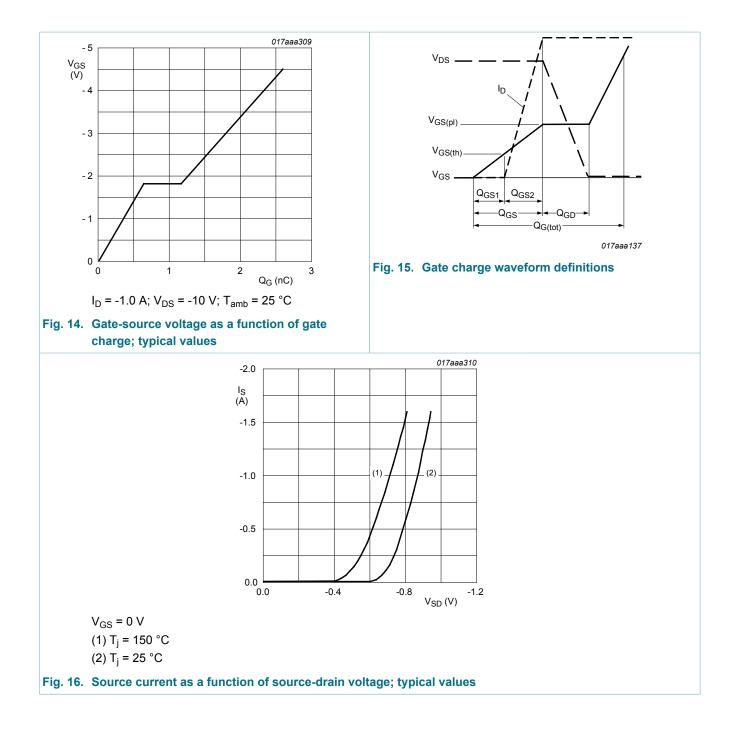
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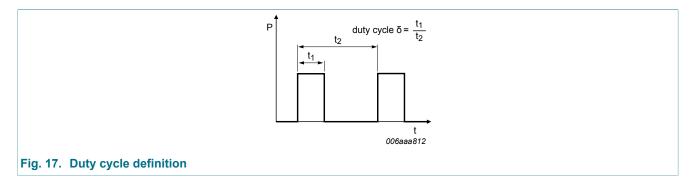
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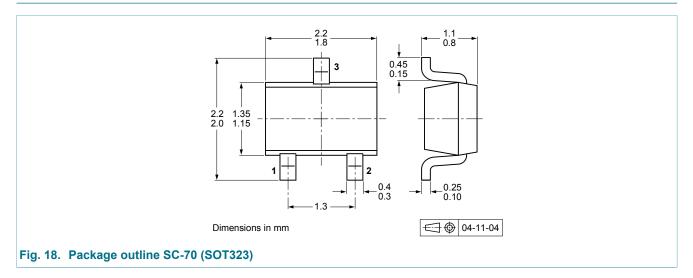


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11. Test information

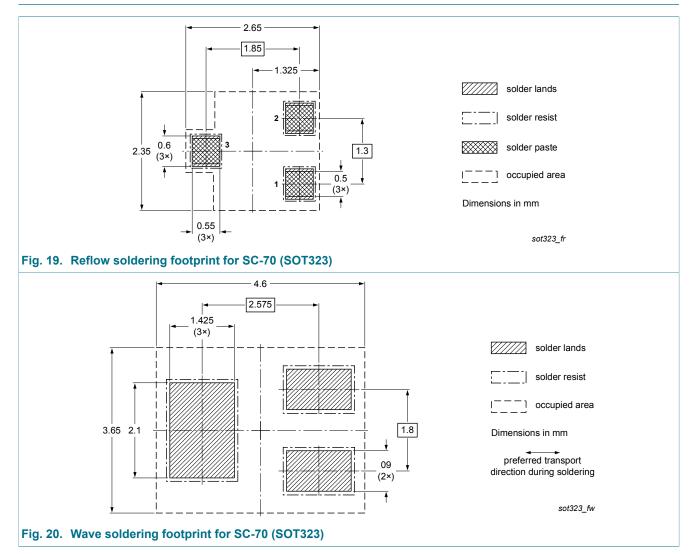


12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMF170XP v.2	20131029	Product data sheet	-	PMF170XP v.1			
Modifications:	Figure 13 corrected	Figure 13 corrected					
PMF170XP v.1	20110902	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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